

# SS10P2CL, SS10P3CL

AUTOMOTIVE

Available

RoHS

HALOGEN

### Vishay General Semiconductor

# **High Current Density Surface Mount Dual Common-Cathode Schottky Rectifiers**



# **TO-277A (SMPC)**

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
V <sub>RRM</sub>	20 V, 30 V				
I <sub>FSM</sub>	200 A				
E <sub>AS</sub>	20 mJ				
V <sub>F</sub> at I <sub>F</sub> = 5 A	0.338 V				
T <sub>J</sub> max.	150 °C				

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

#### **FEATURES**

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level J-STD-020, 1, per LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **MECHANICAL DATA**

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	SS10P2CL	SS10P3CL	UNIT	
Device marking code			S102CL	S103CL		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	20	30	V	
Maximum average forward rectified current (fig. 1)	total device	1	10		А	
	per diode	I <sub>F(AV)</sub>	5.0			
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	200		А	
Non-repetitive avalanche energy at 25 °C, I <sub>AS</sub> = 2 A per diode		E <sub>AS</sub>	20		mJ	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150		°C	

# SS10P2CL, SS10P3CL

# Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.391	-	V	
	I <sub>F</sub> = 5.0 A			0.440	0.52		
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.272	-		
	I <sub>F</sub> = 5.0 A			0.338	0.42		
Reverse current per diode	Rated V <sub>R</sub>	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	95	850	μΑ	
		T <sub>A</sub> = 125 °C		37	55	mA	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	560	-	pF	

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SS10P2CL SS10P3CL		UNIT		
Typical thermal resistance per diode	R <sub>θJA</sub> <sup>(1)</sup>	60		°C/W		
Typical thermal resistance per diode	$R_{ heta JL}$	3				

#### Note

<sup>(1)</sup> Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS103CL-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel		
SS103CL-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel		
SS103CLHM3/86A <sup>(1)</sup>	0.10	86A	1500	7" diameter plastic tape and reel		
SS103CLHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel		

#### Note

(1) Automotive grade





# Vishay General Semiconductor

#### **RATINGS AND CHARACTERISTICS CURVES**

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$ 

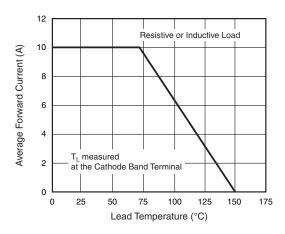


Fig. 1 - Maximum Forward Current Derating Curve

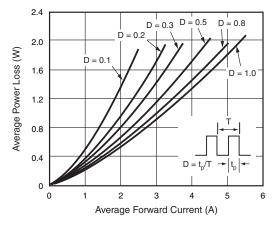


Fig. 2 - Forward Power Loss Characteristics Per Diode

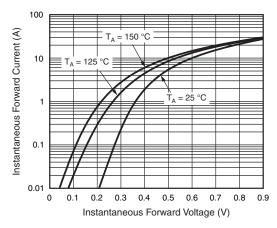


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

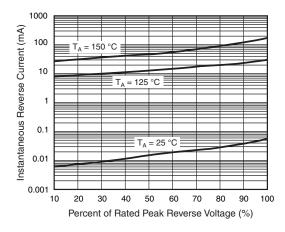


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

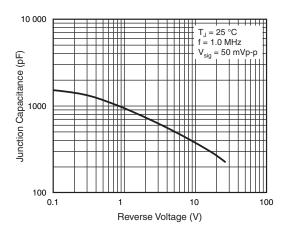


Fig. 5 - Typical Junction Capacitance Per Diode

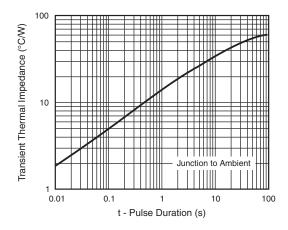


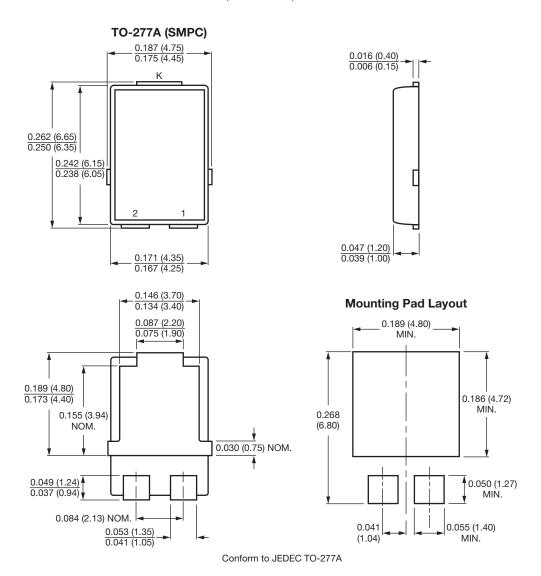
Fig. 6 - Typical Transient Thermal Impedance Per Diode

# SS10P2CL, SS10P3CL

# Vishay General Semiconductor



#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





# **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

### **ПОСТАВКА** ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

многоканальный

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

# Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

### http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru\_6 moschip.ru 4 moschip.ru 9